NSN 5961-01-058-9390

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-058-9390 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Overall Height:** 0.200 inches **Overall Width:** 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 40.0 collector to emitter voltage, dc all transistor and 50.0 collector to base voltage, dc all transistor **Current Rating Per Characteristic:** 1.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector preset all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 8 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0